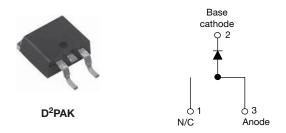
VS-MBRB1635PbF, VS-MBRB1645PbF

Vishay Semiconductors

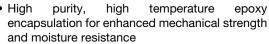
High Performance Schottky Rectifier, 16 A



PRODUCT SUMMARY								
Package	TO-263AB (D ² PAK)							
I _{F(AV)}	16 A							
V_{R}	35 V, 45 V							
V _F at I _F	0.63							
I _{RM}	40 mA at 125 °C							
T _J max.	150 °C							
Diode variation	Single die							
E _{AS}	24 mJ							

FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop





HALOGEN

FREE

· Guard ring for enhanced ruggedness and long

- term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	16	А					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1800	Α					
V _F	16 A _{pk} , T _J = 125 °C	0.57	V					
T _J		-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBRB1635PbF VS-MBRB1645PbF UNITS								
Maximum DC reverse voltage	V_{R}	35	45	V				
Maximum working peak reverse voltage	V_{RWM}	35	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	DITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 134 °C, rated V _R	T _C = 134 °C, rated V _R					
Non-repetitive peak surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse Following any rated load condition and with rated V _{RRM} applied		1800	А			
		Surge applied at rated load condition half wave single phase 60 Hz		150				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	Α			



VS-MBRB1635PbF, VS-MBRB1645PbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63	V			
Maximum forward voltage drop	VFM ('')	10 A	T _J = 125 °C	0.57	V			
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA			
reverse current	'RM \''	T _J = 125 °C	hated DC voltage	40				
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	1400	pF				
Typical series inductance	L _S	Measured lead from top o	8.0	nΗ				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature	range	TJ		-65 to +150	°C		
Maximum storage temperature	range	T _{Stg}		-65 to +175	C		
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.50	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque -	maximum			12 (10)	(lbf \cdot in)		
Marking device			Case style D ² PAK	MBRE	31635		



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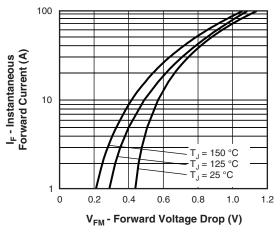


Fig. 1 - Maximum Forward Voltage Drop Characteristics

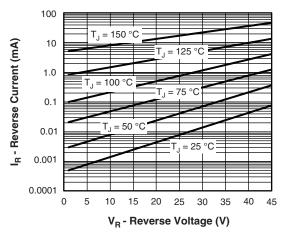


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

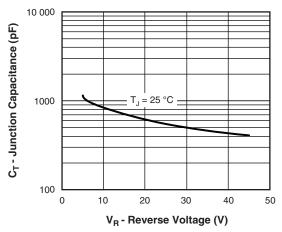


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

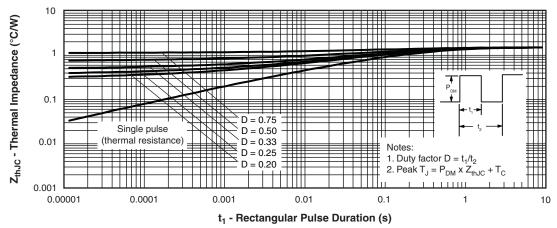


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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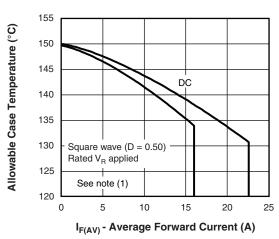
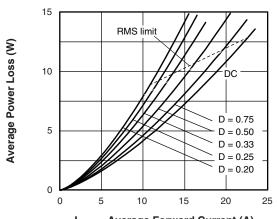


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



I_{F(AV)} - Average Forward Current (A)



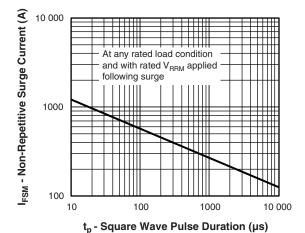


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

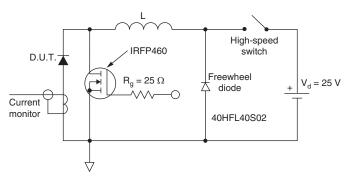


Fig. 8 - Unclamped Inductive Test Circuit

Note

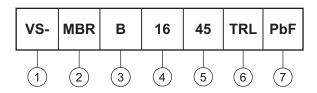
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \text{ applied} \\ \end{array}$

VS-MBRB1635PbF, VS-MBRB1645PbF

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Essential part number

B = surface mount

Current rating (16 = 16 A)

5 - Voltage code = V_{RRM} 35 = 35 V 45 = 45 V

6 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

7 - PbF = lead (Pb)-free

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBRB1635PbF	50	1000	Antistatic plastic tubes							
VS-MBRB1635TRRPbF	800	800	13" diameter reel							
VS-MBRB1635TRLPbF	800	800	13" diameter reel							
VS-MBRB1645PbF	50	1000	Antistatic plastic tubes							
VS-MBRB1645TRRPbF	800	800	13" diameter reel							
VS-MBRB1645TRLPbF	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95407					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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